PTO-1449 REPRODUCED

INFORMATION DISCLOSURE CITATION IN AN APPLICATION

May 20, 2002

ATTORNEY DOCKET NO.	APPLICATION NO.
1866.2005-000	10/037,461
APPLICANT: Richard Sahara et al.	
FILING DATE: November 9, 2001	GROUP: 2881

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE IF APPROPRIATE
DW	AA	4,719,636	1/12/88	Yamaguchi	372	50	
	AB	6,028,881	2/22/00	Ackerman et al.	372	75	
	AC	6,108,469	8/22/00	Chen	385	24	
	AD	6,122,299	9/19/00	DeMars et al.	372	20	
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION YES	TRANSLATION NO
	AL							
	AM							
	AN							
	AO							
	AP							
	AQ							

OTHER DOCUMENTS ***(Including Author, Title, Date, Pertinent Pages, Etc.)***

DW	AR	Kazmierski, Christophe, et al., "1.5μm DFB Lasers with New Current-Induced Gain Gratings," *IEEE Journal of Selected Topics in Quantum Elec.*, 1(2): 371-374 (1995).
DW	AS	Nakano, Yoshiaki, et al., " Reduction of Excess Intensity Noise Induced by External Reflection in a Gain-Coupled Distributed Feedback Semiconductor Laser," *IEEE Journal of Quantum Electronics*, 27(6): 1732-1735 (1991).
DW	AT	Huang, Yidong,et al., "Isolator-Free 2.5 Gb/s 80-km Transmission by Directly Modulated λ/8 Phase-Shifted DFB-LDs Under Negative Feedback Effect of Mirror Loss," *IEEE Photonics Technology Letters*, 13(3): 245-247 (2001).

EXAMINER	DATE CONSIDERED
	10/06/03

PTO-1449 REPRODUCED

INFORMATION DISCLOSURE CITATION IN AN APPLICATION

May 20, 2002

ATTORNEY DOCKET NO.	APPLICATION NO.
1866.2005-000	10/037,461
APPLICANT: Richard Sahara et al.	
FILING DATE: November 9, 2001	GROUP: 2881

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION YES	NO

OTHER DOCUMENTS *(Including Author, Title, Date, Pertinent Pages, Etc.)*

DW	AU	Thedrez, B., et al., "1.3µm tapered DFB lasers for isolator-free 2.5 Gbits all-optical networks," OPTO+, Groupement d'Intérêt Economique, Alcatel Corporate Research Center, Marcoussis, France.
	AV	Xing-sha, Zhou and Peida, Ye, "Intensity Noise of Semiconductor Laser In Presence Of Arbitrary Optical Feedback," *Electronics Letters*, 25(7): 446-447 (1989).
	AW	Schunk, N. and Petermann, K., " Measured Feedback-induced Intensity Noise for 1.3µm DFB Laser Diodes," *Electronics Letters*, 25(1): 63-64 (1989).
	AX	Favre, F., "Sensitivity to External Feedback For Gain-Coupled DFB Semiconductor Lasers," *Electronics Letters*, 27(5): 433-435 (1991).
	AY	Nakano, Y., et al., "Resistance to External Optical Feedback in a Gain-Coupled Semiconductor DFB Laser," University of Tokyo, Bunkyo-ku, Tokyo 113, Japan.
✓	AZ	"QLM6S891, 2mW 1625nm OSC Source DFB Laser", Product Brochure, Corning Incorporated, One Riverfront Plaza, Corning, NY 14831-0001(2001).

EXAMINER: DW

DATE CONSIDERED: 10/06/03